

## 2N4391, 2N4392, 2N4393

## N-Channel Silicon Junction Field-Effect Transistor

- Low On Resistance Analog Switches
- Choppers
- Commutators

**Absolute maximum ratings at  $T_A = 25^\circ\text{C}$** 

Reverse Gate Source & Reverse Gate Drain Voltage	- 40 V
Continuous Forward Gate Current	50 mA
Continuous Device Power Dissipation	1.8 W
Power Derating	12 mW/ $^\circ\text{C}$

**At 25°C free air temperature  
Static Electrical Characteristics**

		2N4391		2N4392		2N4393		Process NJ132		
		Min	Max	Min	Max	Min	Max	Unit	Test Conditions	
Gate Source Breakdown Voltage	$V_{(\text{BR})\text{GSS}}$	- 40		- 40		- 40		V	$I_G = - 1\mu\text{A}, V_{DS} = 0\text{V}$	
Gate Reverse Current	$I_{GS}$		- 100		- 100		- 100	pA	$V_{GS} = - 20\text{V}, V_{DS} = 0\text{V}$	
			- 200		- 200		- 200	nA	$V_{GS} = - 20\text{V}, V_{DS} = 0\text{V}$	$T_A = 150^\circ\text{C}$
Gate Source Cutoff Voltage	$V_{GS(\text{OFF})}$	- 4	- 10	- 2	- 5	- 0.5	- 3	V	$V_{DS} = - 20\text{V}, I_D = 1\text{nA}$	
Gate Source Forward Voltage	$V_{GS(\text{F})}$		1		1		1	V	$I_G = 1\text{mA}, V_{DS} = 0\text{V}$	
Drain Saturation Current (Pulsed)	$I_{DSS}$	50	150	25	75	5	30	mA	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$	
Drain Cutoff Current	$I_{D(\text{OFF})}$						100	pA	$V_{DS} = 20\text{V}, V_{GS} = - 5\text{V}$	
							200	nA	$V_{DS} = 20\text{V}, V_{GS} = - 5\text{V}$	$T_A = 150^\circ\text{C}$
					100			pA	$V_{DS} = 20\text{V}, V_{GS} = - 7\text{V}$	
				200				nA	$V_{DS} = 20\text{V}, V_{GS} = - 7\text{V}$	$T_A = 150^\circ\text{C}$
			100					pA	$V_{DS} = 20\text{V}, V_{GS} = - 12\text{V}$	
			200					nA	$V_{DS} = 20\text{V}, V_{GS} = - 12\text{V}$	$T_A = 150^\circ\text{C}$
Drain Source ON Voltage	$V_{DS(\text{ON})}$					0.4	V	$V_{GS} = 0\text{V}, I_D = 3\text{mA}$		
					0.4		V	$V_{GS} = 0\text{V}, I_D = 6\text{mA}$		
			0.4				V	$V_{GS} = 0\text{V}, I_D = 12\text{mA}$		
Static Drain Source ON Resistance	$r_{DS(\text{ON})}$		30		60		100	$\Omega$	$V_{GS} = 0\text{V}, I_D = 1\text{mA}$	

**Dynamic Electrical Characteristics**

Drain Source ON Resistance	$r_{ds(\text{on})}$		30		60		100	$\Omega$	$V_{GS} = 0\text{V}, I_D = 0\text{A}$	$f = 1\text{ kHz}$
Common Source Input Capacitance	$C_{iss}$		14		14		14	pF	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$	$f = 1\text{ kHz}$
Common Source Reverse Transfer Capacitance	$C_{rss}$						3.5	pF	$V_{DS} = 0\text{V}, V_{GS} = - 5\text{V}$	$f = 1\text{ kHz}$
					3.5			pF	$V_{DS} = 0\text{V}, V_{GS} = - 7\text{V}$	$f = 1\text{ kHz}$
			3.5					pF	$V_{DS} = 0\text{V}, V_{GS} = - 12\text{V}$	$f = 1\text{ kHz}$

**Switching Characteristics**

Turn ON Delay Time	$t_{d(\text{on})}$		15		15		15	ns	$V_{DD} = 10\text{V}, V_{GS(\text{ON})} = 0\text{V}$	
Rise Time	$t_r$		5		5		5	ns	<b>2N4391 2N4392 2N4393</b>	
Turn OFF Delay Time	$t_{d(\text{off})}$		20		35		50	ns	$I_{D(\text{ON})}$	12 6 3 mA
Fall Time	$t_f$		15		20		30	ns	$V_{GS(\text{OFF})}$	- 12 - 7 - 5 V

**TO-18 Package**

See Section G for Outline Dimensions

**Pin Configuration**

1 Source, 2 Drain, 3 Gate &amp; Case

**Surface Mount**

SMP4391, SMP4392, SMP4393

